# NSN 5962-01-357-6619

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View Online at https://aerobasegroup.com/nsn/5962-01-357-6619

## **Body Length:**

Between 1.440 inches and 1.490 inches

## Body Width:

Between 0.500 inches and 0.610 inches

## **Body Height:**

0.225 inches

### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

### **Features Provided:**

Bipolar and programmable and w/enable and 3-state output and w/disable

#### Inclosure Material:

Ceramic

#### Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

Transistor-transistor logic

#### Input Circuit Pattern:

17 input

## **Current Rating Per Characteristic:**

180.00 milliamperes reverse current, dc absolute

# **Terminal Surface Treatment:**

Solder

### Voltage Rating And Type Per Characteristic:

7.0 volts power source

### **Capitance Rating Per Characteristic:**

7.00 input picofarads and 17.00 output picofarads

### Time Rating Per Chacteristic:

80.00 nanoseconds access

#### Memory Device Type:

Pal

# Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## Terminal Type And Quantity:

28 printed circuit

# Shelf Life:

N/a

## Unit Of Measure:

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# Demilitarization:

Yes - demil/mli

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